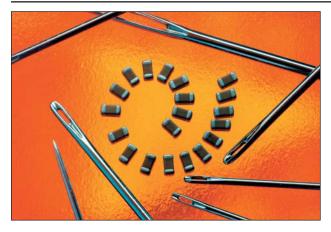
StaticGuard

AVX Multilayer Ceramic Transient Voltage Suppressors ESD Protection for CMOS, Bi Polar and SiGe Based Systems



GENERAL DESCRIPTION

The StaticGuard Series are low capacitance versions of the TransGuard and are designed for general ESD protection of CMOS, Bi-Polar, and SiGe based systems. The low capacitance makes these products suitable for use in high speed data transmission lines.

GENERAL CHARACTERISTICS

- Operating Temperature: -55°C to 125°C
- Working Voltage: ≤ 18Vdc
- Case Size: 0402, 0603, 0805, 1206

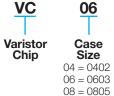
FEATURES

- Typical ESD failure voltage for CMOS and/or Bi Polar is ≥ 200V
- Low capacitance (<200pF) is required for high-speed data transmission.
- Low leakage current (I_L) is necessary for battery operated equipment.
- 15kV ESD pulse (air discharge) per IEC 61000-4-2, Level 4, generates < 20 millijoules of energy.

APPLICATIONS

- Sensors
- CMOS
- SIGe based systems
- Higher speeed data lines
- Capacitance sensitive applications and more

HOW TO ORDER



12 = 1206

LC 06

Low Cap Design

18 Working Voltage

Rating 18 = 18.0VDC A = 0.10 JoulesV = 0.02 Joules

X Energy

Voltage 500 = 50VX = 0.05 Joules

500 Clamping

Packaging (PCS/REEL) D = 1,000*

R

R = 4,000*T = 10,000* W = 10,000** **Termination** P = Ni/Sn

*Not available for 0402 **Only available for 0402

ELECTRIAL CHARACTERISTICS

AVX PN	V _W (DC)	V _W (AC)	V _B	V _C	I _{vc}	ΙL	E _T	I _P	Cap	Freq	Size
VC04LC18V500	≤18.0	≤14.0	25-40	50	1	10	0.02	15	40	М	0402
VC06LC18X500	≤18.0	≤14.0	25-40	50	1	10	0.05	30	50	М	0603
VC08LC18A500	≤18.0	≤14.0	25-40	50	1	10	0.1	30	80	М	0805
VC12LC18A500	≤18.0	≤14.0	25-40	50	1	10	0.1	30	200	K	1206

V...(DC) DC Working Voltage [V] V_w(AC) AC Working Voltage [V]

Typical Breakdown Votage (Min-Max) V_R [V @ 1mAnc, 25°C]

Clamping Voltage IV @ I.... Test Current for V_c [A, 8x20µs] Maximum leakage current at the working

voltage, 25°C [μA]

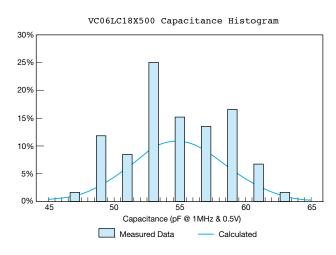
Transient Energy Rating [J, 10x1000µS] Peak Current Rating [A, 8x20µS]

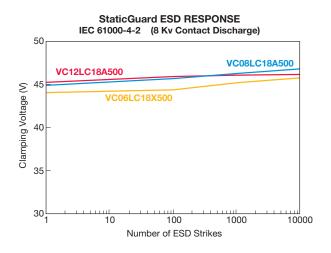
Typical capacitance [pF] @ frequency specified and $0.5V_{\text{RMS}}$, 25°C , K = 1kHz, M = 1MHz

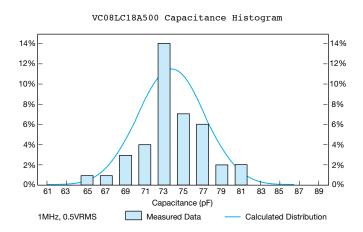
StaticGuard

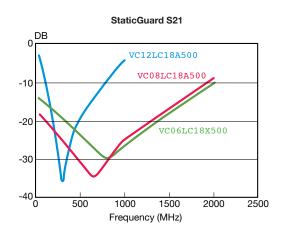
AVX Multilayer Ceramic Transient Voltage Suppressors ESD Protection for CMOS, Bi Polar and SiGe Based Systems

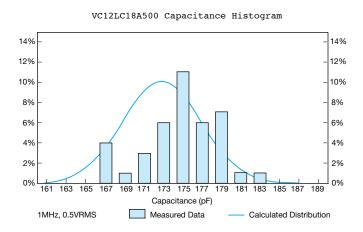
TYPICAL PERFORMANCE DATA

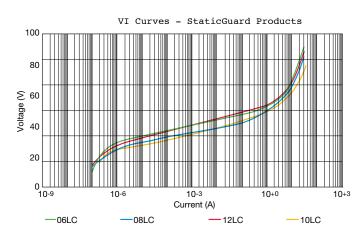












StaticGuard

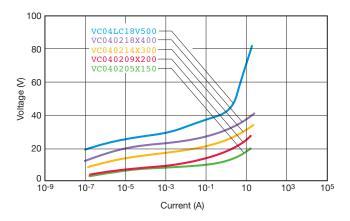


AVX Multilayer Ceramic Transient Voltage Suppressors

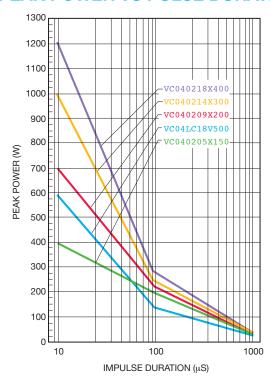
TYPICAL PERFORMANCE CURVES (0402 CHIP SIZE)

VOLTAGE/CURRENT CHARACTERISTICS

Multilayer construction and improved grain structure result in excellent transient clamping characteristics up to 20 amps peak current, while maintaining very low leakage currents under DC operating conditions. The VI curves below show the voltage/current characteristics for the 5.6V, 9V, 14V, 18V and low capacitance StaticGuard parts with currents ranging from parts of a micro amp to tens of amps.



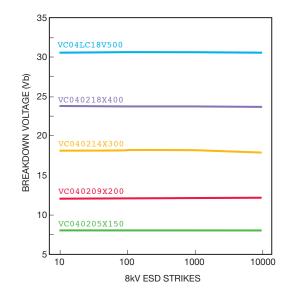
PEAK POWER VS PULSE DURATION



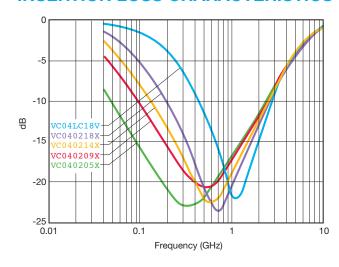
PULSE DEGRADATION

Traditionally varistors have suffered degradation of electrical performance with repeated high current pulses resulting in decreased breakdown voltage and increased leakage current. It has been suggested that irregular intergranular boundaries and bulk material result in restricted current paths and other non-Schottky barrier paralleled conduction paths in the ceramic. Repeated pulsing of TransGuard® transient voltage suppressors with 150Amp peak 8 x 20µS waveforms shows negligible degradation in breakdown voltage and minimal increases in leakage current.

ESD TEST OF 0402 PARTS



INSERTION LOSS CHARACTERISTICS



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

AVX:

<u>VC12LC18A500DP VC08LC18A500DP VC04LC18V500RP VC04LC18V500WP VC06LC18X500RM VC06LC18X500DP VC06LC18X500RP VC08LC18A500TP VC06LC18X500D VC06LC18X500R VC12LC18A500RP VC12LC18A500TP VC06LC18X500TP VC06LC18X500D VC06LC18X500R VC12LC18A500RP VC12LC18A500TP VC06LC18X500TP VC06LC18X</u>